

Electronic Supplementary Information (ESI)

Improving Low-Energy Boron/Nitrogen Ion Implantation in Graphene by Ion Bombardment at Oblique Angles

Zhitong Bai,^a Lin Zhang,^a and Ling Liu^{a*}

^a Department of Mechanical and Aerospace Engineering, Utah State University, Logan, UT 84322, USA

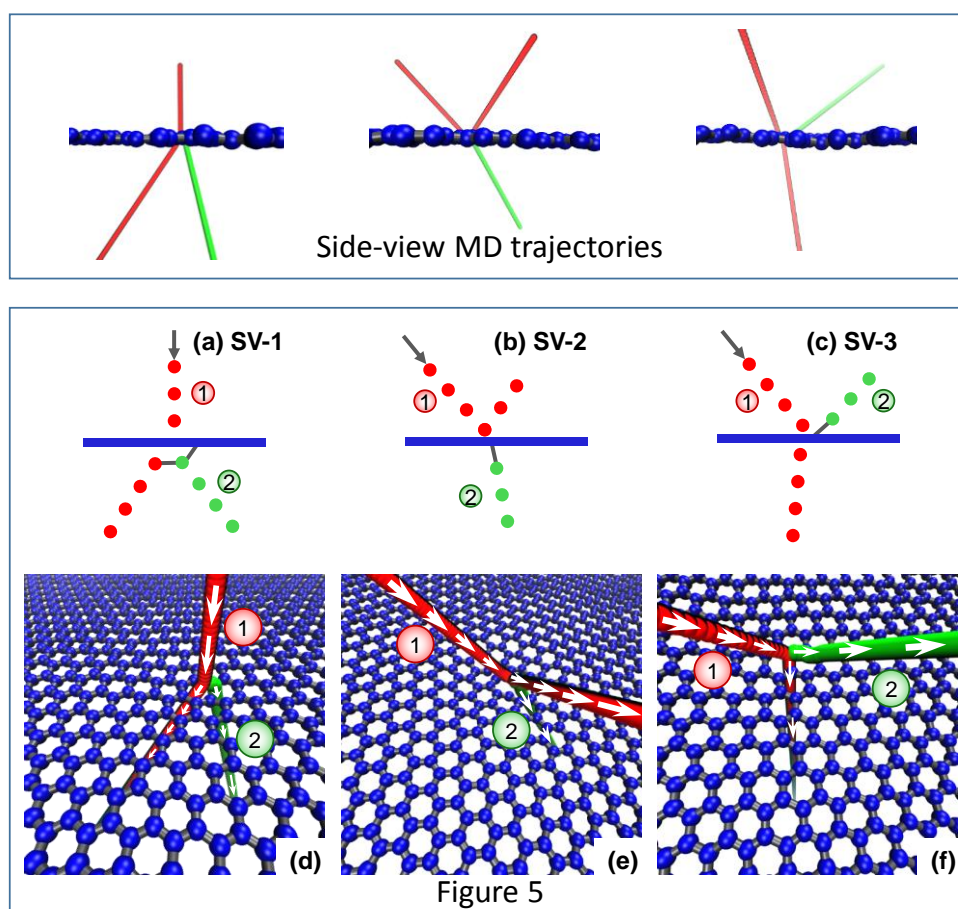


Figure S1. Side-view MD trajectories that complement the snapshots shown in Figure 5(d-f). These side-view MD trajectories can be directly compared with the mechanism schematics shown in Figure 5(a-c).

* Email: ling.liu@usu.edu

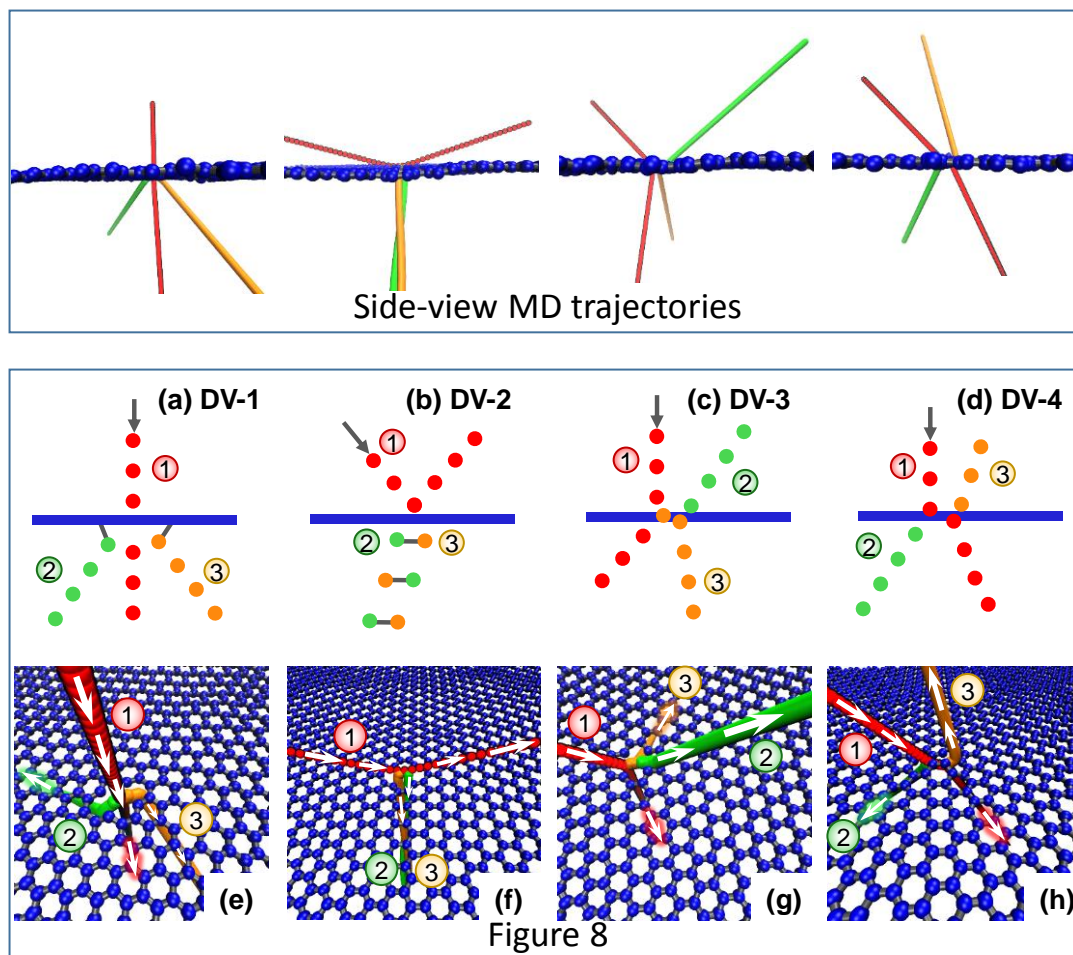


Figure S2. Side-view MD trajectories that complement the snapshots shown in Figure 8(e-h). These side-view MD trajectories can be directly compared with the mechanism schematics shown in Figure 8(a-d).